

TECHNICAL DATA DATA SHEET 4618, REV.-

HERMETIC POWER SCHOTTKY RECTIFIER

(SINGLE / DUAL)

DESCRIPTION: A 200 VOLT, 15 AMP, POWER SCHOTTKY RECTIFIER IN A HERMETIC LCC-3P PACKAGE.

MAXIMUM RATINGS

ALL RATINGS ARE @ $T_C = 25$ °C UNLESS OTHERWISE SPECIFIED.

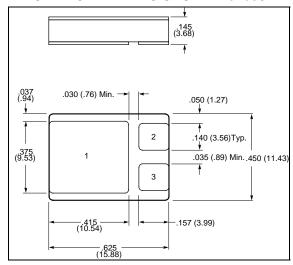
RATING	SYMBOL	MAX.	UNITS
PEAK INVERSE VOLTAGE	PIV	200	Volts
MAXIMUM DC OUTPUT CURRENT With Cathode Maintained (@ T_c =100 $^{\circ}$ C) (Single)	Io	15	Amps
MAXIMUM DC OUTPUT CURRENT With Cathode Maintained (@ T_C =100 $^{\rm O}$ C) (Common Cathode)	Io	15	Amps
MAXIMUM NONREPETITIVE FORWARD SURGE CURRENT (t = 8.3ms, Sine)	I _{FSM}	200	Amps
MAXIMUM JUNCTION CAPACITANCE (V _r =5V)	C _T	300	pF
MAXIMUM THERMAL RESISTANCE		1.21	°C/W
MAXIMUM OPERATING AND STORAGE TEMPERATURE RANGE		-65 to + 200	°C

ELECTRICAL CHARACTERISTICS

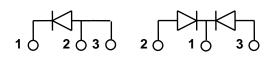
CHARACTERISTIC				
MAXIMUM FORWARD VOLTAGE DROP, Pulsed (I _f = 15 Amps)				
	T _J = 25 °C	V_{f}	1.01	Volts
	T _J = 125 °C		0.85	
MAXIMUM REVERSE CURRENT (I _r @ 200 V PIV)				
	T _J = 25 °C	I _r	0.015	mA
	T _J = 125 °C		1.0	

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MECHANICAL DIMENSIONS: IN Inches / mm





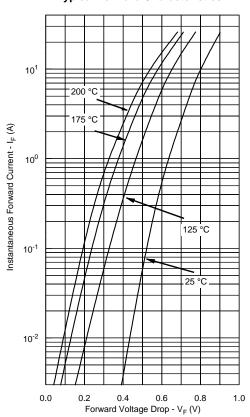


LCC-3P

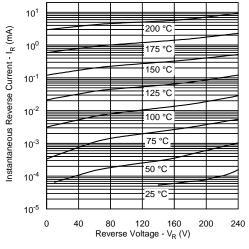
PINOUT TABLE

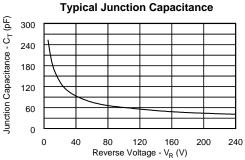
DEVICE TYPE	PIN 1	PIN 2	PIN 3
SINGLE RECTIFIER	CATHODE	ANODE	ANODE
COMMON CATHODE	COMMON CATHODE	ANODE 1	ANODE 2

Typical Forward Characteristics



Typical Reverse Characteristics







TECHNICAL DATA

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